

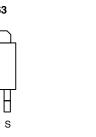
Automotive N-Channel 40 V (D-S) 175 °C MOSFET

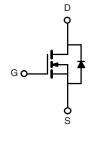
PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 V$	0.0019				
I _D (A)	120				
Configuration	Single				



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Top View

N-Channel MOSFET

FEATURES

- TrenchFET[®] Power MOSFET
- · Package with Low Thermal Resistance
- AEC-Q101 Qualified^d
- 100 % R_a and UIS Tested
- For definitions of compliance please see www.vishay.com/doc?99912



FREE

Material categorization:

ORDERING INFORMATION					
Package	TO-263				
Lead (Pb)-free and Halogen-free	SQM120N04-1m9-GE3				

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \degree C$, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	40	N		
Gate-Source Voltage		V _{GS}	± 20	V		
Continuous Drain Current ^a	T _C = 25 °C	- I _D	120			
	T _C = 125 °C		120			
Continuous Source Current (Diode Conduction) ^a		I _S	120	А		
Pulsed Drain Current ^b		I _{DM}	480			
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	84			
Single Pulse Avalanche Energy		E _{AS}	352	mJ		
Maximum Power Dissipation ^b	T _C = 25 °C	D	300	W		
	T _C = 125 °C	P _D	100	vv		
Operating Junction and Storage Temperature Rar	nge	T _J , T _{stg}	- 55 to + 175	°C		

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-Ambient P	PCB Mount ^c	R _{thJA}	40	°C/W		
Junction-to-Case (Drain)		R _{thJC}	0.5	C/VV		

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$

c. When mounted on 1" square PCB (FR-4 material).

d. Parametric verification ongoing.

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SQM120N04-1m9



Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static	-	-						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		40	-	-	v	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$		3.0	3.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 175 °C	-	-	250		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	120	-	-	Α	
		V _{GS} = 10 V	I _D = 30 A	-	0.0015	0.0019		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A, T _J = 125 °C	-	-	0.0030	Ω	
		$V_{GS} = 10 V$	I _D = 30 A, T _J = 175 °C	A, TJ = 175 °C		0.0037	1	
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 30 A		-	166	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	7030	8790		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{GS} = 0 V V _{DS} = 25 V, f = 1 MHz		1180	1475	pF	
Reverse Transfer Capacitance	C _{rss}	1		-	445	555	1	
Total Gate Charge ^c	Qg			-	180	270		
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 10 \text{ V}, I_D = 16 \text{ A}$	-	44	-	nC	
Gate-Drain Charge ^c	Q _{gd}	1		-	40	-		
Gate Resistance	Rg	f = 1 MHz		4.5	9.13	13.7	Ω	
Turn-On Delay Time ^c	t _{d(on)}	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 20 \; V, \; R_{\text{L}} = 1 \; \Omega \\ I_{\text{D}} \cong 20 \; A, \; V_{\text{GEN}} = 10 \; V, \; R_{\text{g}} = 1 \; \Omega \end{array}$		-	12	18		
Rise Time ^c	t _r			-	5	8	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	248	370		
Fall Time ^c	t _f			-	92	145		
Source-Drain Diode Ratings and Chara	acteristics ^b	·			•			
Pulsed Current ^a	I _{SM}			-	-	480	Α	
Forward Voltage	V _{SD}	I _F = 85 A, V _{GS} = 0		_	0.86	1.5	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

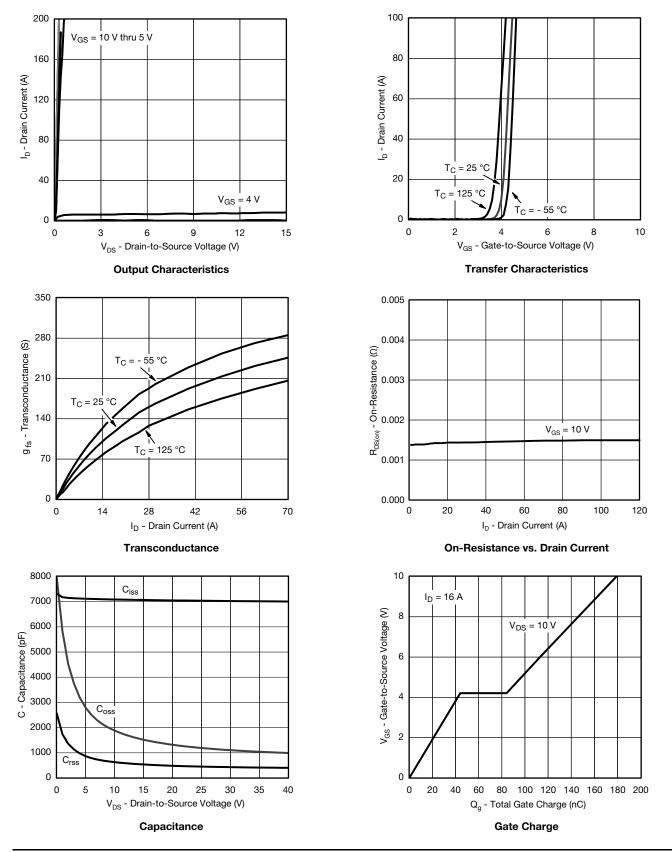
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



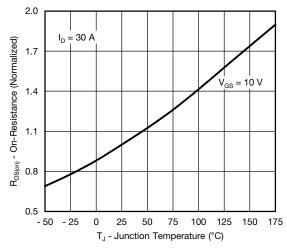
S12-0569-Rev. A, 09-Apr-12

Document Number: 63810

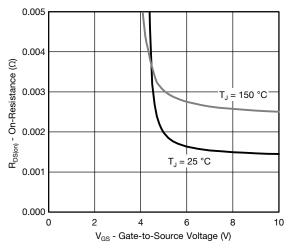
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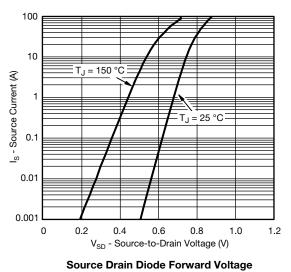
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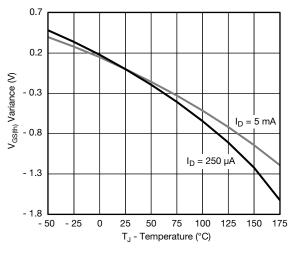


On-Resistance vs. Junction Temperature

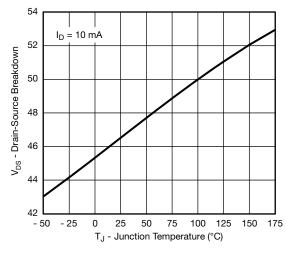


On-Resistance vs. Gate-to-Source Voltage









Drain Source Breakdown vs. Junction Temperature

4

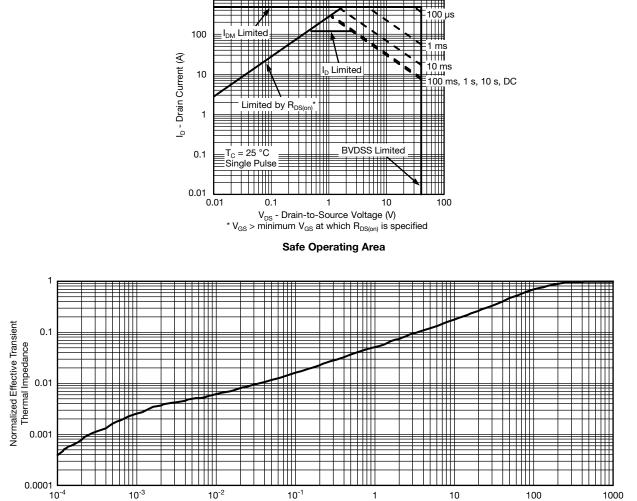
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)

1000

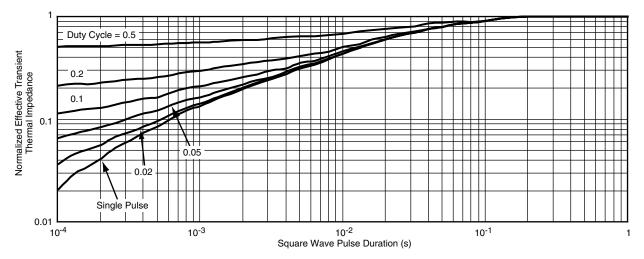


Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

· The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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TO-263 (D²PAK): 3-LEAD

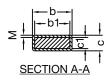








DETAIL A (ROTATED 90°)



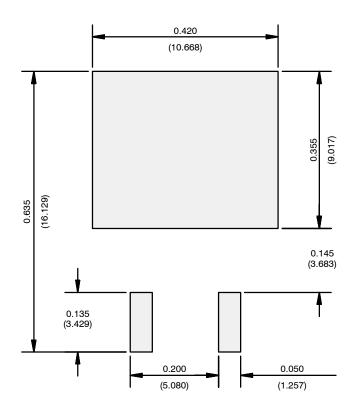
		INC	HES	MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
A		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
<u>1</u>	Thin lead	0.013	0.017	0.330	0.431	
c1	Thick lead	0.023	0.027	0.584	0.685	
c2		0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
E2		0.355	0.375	9.017	9.525	
E3		0.072	0.078	1.829	1.981	
	e 0.100 BSC		BSC	2.54 BSC		
	К	0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.254 BSC		
М		-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843						

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 % of L1 can fall above seating plane by
- max. 8 mils.3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
 - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.
- 6. This feature is for thick lead.



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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